ОртіТгаск™

850 nm IR LED

Specifications:

Product: Infrared LED lamp
Product Description: Stem type LED
with epoxy resin lens

Material: AlGaAs

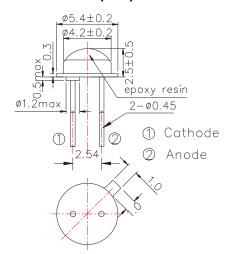
Stem: TO-46 with reflector

Peak Wavelength:850 nmOutput Power:44 mW

Features:

- · Ultra-wide viewing angle
- · High efficiency
- · High reliability
- · Lead-free RoHS compliant

Dimensions (mm):



Absolute Maximum Ratings:

Parameter	Symbol	Maximum Rated Value	Ambient Temperature
Power Dissipation	Po	160 mW	Ta = 25 °C
Forward Current	lF	100 mA	Ta = 25 °C
Pulse Forward Current ¹	IFP	1000 mA	Ta = 25 °C
Reverse Voltage	VR	5 V	Ta = 25 °C
Juntion Temperature	TJ	100 °C	
Thermal Resistance	Rthja	240 K/W	
Operating Temperature	Topr	-30 ~ +80 °C	
Storage Temperature	Tstg	-30 ~ +100 °C	
Soldering Temperature ²	TsoL	265 °C	

Electro-Optical Characteristics:

Parameter	Symbol	Condition	Minimum	Typical	Maximum
Forward Voltage	VF	IF = 50 mA DC		1.45 V	1.6 V
		$I_F = 100 \text{ mA}, tp = 20 \text{ ms}$		1.50 V	1.7 V
Reverse Current	lR	$V_R = 5 V$			10 uA
Total Radiated Power ³	Po	Ir = 50 mA DC	16 mW	22 mW	
		$I_F = 100 \text{ mA}, tp = 20 \text{ ms}$		44 mW	
Radiant Intensity⁴	lε	Ir = 50 mA DC		8 mW / sr	
		$I_F = 100 \text{ mA}, tp = 20 \text{ ms}$		16 mW / sr	
Peak Wavelength	λР	IF = 50 mA DC	840 nm	850 nm	860 nm
Half Width	Δλ	Ir = 50 mA DC		40 nm	
Viewing Half Angle	$\theta\frac{1}{2}$	IF = 50 mA DC		±60°	
Rise Time	tr	IF = 50 mA DC		15 ns	
Fall Time	tf	IF = 50 mA DC		10 ns	

Notes:

- 1. Duty = 1% and Pulse Width = 10 us.
- 2. Soldering condition must be completed within 3 seconds at 265 $^{\circ}\text{C}$
- 3. Measured by Photodyne #500.
- 4. Measured by Tektronix J-6512.